

TE1B Datasheet

TE1B is a bias board for Microsemi drivers and modules, providing easy control over three pairs of gate and drain voltages.

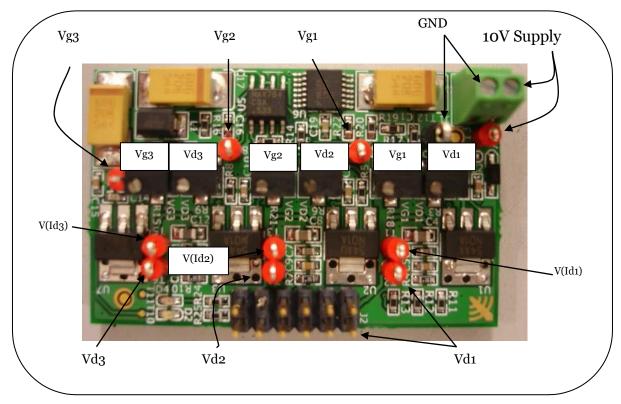


Figure 1.TE1B Datasheet

Application Notes:

- 1. Test points for gate and drain voltages are labeled as Vg and Vd, followed by the number.
- 2. Drain current can be measured over two test points denoted by Id's. There is 0.1 Ohm resistor in between these two test points. (i.e. Id = (Vd V(id)) / 0.1)



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